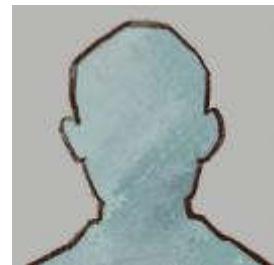


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## 教育和工作经历

2009年7月加入厦门大学物理系，历任助理教授、副教授。

2008年6月至2009年6月，韩国高丽大学电子系博士后。

2008年1月毕业于上海复旦大学微电子学系，获理学博士学位。

## 代表性文章或专著

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#### 科研基金

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#### 任教课程

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